

Crystallization in mass-asymmetric electron-hole bilayers

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We consider a *mass-asymmetric* electron and hole bilayer. Electron and hole Coulomb correlations and electron and hole quantum effects are treated on first principles by path integral Monte Carlo methods. For a fixed layer separation we vary the mass ratio M of holes and electrons between 1 and 100 and analyze the structural changes in the system. While, for the chosen density, the electrons are in a nearly homogeneous state, the hole arrangement changes from homogeneous to localized, with increasing M which is verified for both, mesoscopic bilayers in a parabolic trap and for a macroscopic system.

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1 Introduction

Strongly correlated Coulomb systems are of growing interest in many fields, including plasmas and condensed matter, see e.g. [1] for an overview. In particular, Wigner crystal formation is one of the most prominent correlation phenomena observed in ultracold ions [2], dusty plasmas [3, 4], quantum dots, e.g. [5, 6] and other confined (non-neutral) systems. Recently crystal formation in two-component (neutral) quantum plasmas was demonstrated by simulations [7] confirming early predictions of hole crystallization in semiconductors by Halperin and Rice [8], Abrikosov [9] and others. Interestingly, this is essentially the same physical phenomenon as crystallization of nuclei in White Dwarf stars [10].

A different type of two-component system, standing in between the neutral and non-neutral Coulomb systems, are bilayer containing spatially separated positive and negative charges which are most easily to realize in semiconductors by means of doping (electron-hole bilayers). These systems are of high interest because the strength of the correlations can be tuned by varying the layer separation d . The interplay of intra-layer and inter-layer correlations in classical bilayers has been studied in detail for macroscopic, e.g. [11] and mesoscopic [12, 13] systems. Quantum bilayers have been treated much less, see e.g. [14, 15, 16, 17] and are much poorer understood. In particular, most investigations have considered symmetric bilayers, where the hole to electron mass ratio $M = m_h/m_e$ equals one. However, the typical mass ratio in semiconductors is on the order of $M = 3 \dots 10$, and even exotic materials exist where M reaches 40 [18] or even higher values.

For this reason, in this paper we concentrate on the effect of the mass ratio on crystal formation in quantum electron-hole bilayers. Varying M from 1 to 100 at low temperature and high density, we can tune the hole behavior from delocalized (quantum) to localized (quasi-classical) while the electrons remain delocalized all the time. As was recently observed for bulk semiconductors [7], holes undergo a phase transition to a crystalline state if the mass ratio exceeds a critical value of $M_{cr} \approx 80$. Here, we extend this analysis to bilayers where M_{cr} depends on d and the in-layer particle density. To reduce the complexity of the problem, here we will keep d fixed. The complicated overlap of correlation and quantum effects of both, electrons and holes, is fully taken care of by performing first-principle path integral simulations. We present results for two types of e-h bilayers: a mesoscopic system of $N = 36$ particles in a parabolic trap and for a macroscopic system of the same density.

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2 Model and Parameters

The physical realization of the mass asymmetric bilayers considered here can be a system of two coupled quantum wells filled with electrons and holes, respectively. An additional in-plane potential can produce the lateral confinement of the carriers leading to a system of two coupled quantum dots. Recently, we have analyzed in detail a possible realization of a parabolic in-plane potential using the idea of the quantum Stark confinement [19]. An inhomogeneous electric field applied perpendicular to the QW plane changes the energy of a particle in the quantum well because the penetration of a particle inside the barrier material depends on the strength of the electric field. For example, in GaAs and ZnSe based QW one can achieve harmonic trap frequencies from 1 GHz to 1 THz for typical electric field strengths of 10–20 kV/cm.

In this paper, we approximate two coupled QWs by a model of two vertically separated 2D layers populated with N_e electrons and N_h holes (we consider the case $N_e = N_h = N=2$). The charges interact via the Coulomb potential. The underlying Hamiltonian is well defined and is of practical importance for semiconductor heterostructures

$$\hat{H} = \hat{H}_e + \hat{H}_h + \sum_{i=1}^N \sum_{j=1}^N \frac{e_i e_j}{\sqrt{(x_i - x_j)^2 + (z_i - z_j)^2}}; \quad \hat{H}_a = \sum_{i=1}^N \left(\frac{\hbar^2}{2m_a} r_{i,a}^2 + \frac{m_a}{2} \omega_a^2 r_{i,a}^2 \right); \quad (1)$$

where the electrons (e) are confined to the plane $z = 0$ and the holes (h) to the plane $z = d$; also r_i and r_j are the in-plane 2D radius vectors describing the particle coordinates in each layer. In the following all lengths will be given in units of the effective Bohr radius $a_B = \hbar^2 / m_e e^2$. For example, for GaAs and ZnSe quantum wells this results in the length units a_B (GaAs) = 9.98 nm and a_B (ZnSe) = 3.07 nm. Energies and temperatures are measured in Hartree units: 1 Ha (GaAs) = 11.47 meV (133.1 K) and 1 Ha (ZnSe) = 53.93 meV (625.8 K).

For the mesoscopic trapped system the density is controlled by the harmonic trap frequency (we use $m_e \omega_e^2 = m_h \omega_h^2$) and is characterized by the coupling parameter $\alpha = (e^2 / \hbar v_e) = l_0 / a_B$ with $l_0^2 = \hbar / m_e \omega_e$. In this case, the coupling parameter for the holes is related to the electron coupling as $\alpha_h = (m_h / m_e)^{3/4}$. Also for Coulomb systems in a parabolic trap one can find the following useful relations. For two classical particles in a parabolic trap their separation distance r_0 in the ground state is given by: $e^2 / r_0 = m_e \omega_e^2 r_0^2 = 2$. Now we can define the density parameter r_s (in analogy to the Brueckner parameter $r_s = \hbar / m_e v_F$ for macroscopic systems) as follows: $r_s = r_0 / a_B = (2e^2 / m_e \omega_e^2)^{1/3} = a_B = 2^{1/3} \alpha^{-3/4}$. We will use this formula to obtain approximate relations between the densities in the mesoscopic and macroscopic system by relating α , r_s and r_s .

2.1 Numerical details

To solve the problem of N interacting particles described by the Hamiltonian (1) we use the path integral Monte Carlo (PIMC) method. The applied PIMC simulation technique was described in detail in Ref. [20]. The effective interaction potentials used in the expressions for the high-temperature pair density matrices were obtained by using the matrix squaring technique [21, 22].

One of the main obstacles that limit applicability of the PIMC method for systems of particles obeying Fermi statistics is the so called *Fermion sign problem*. Without additional approximations the direct fermionic PIMC simulations are only limited to problems where the degeneracy is not very high. This, certainly depends on the physical situation and is related to the particle density, interaction strength and temperature. Full inclusion of the quantum exchange effects for the number of particles considered here, i.e. $N_{e(h)} = 36$ – 64 , will not be possible without neglecting the spin statistics and permutations in the electron and hole subsystems. However, direct comparison of the PIMC simulations without spin [23] with the results of Ref. [25] which include spin effects show, that the errors introduced by neglecting the spin statistics are of the order of few percents and are completely negligible for $r_s = 10$. The considered here electron densities, i.e. $r_s = 18$, are sufficiently low (for the holes the corresponding parameter $r_s^{(h)}$ is even larger due to their larger mass) and the dominant effect for the interparticle correlations (and in particular for the holes) are driven mainly by the strength of the Coulomb interaction and not by quantum statistics effects. Also, there is no doubt that the spin will have a negligible effect on the localized states of the holes when they form a 2D lattice. Hence, we expect, that the solid-liquid transition investigated in this paper will not be sensitive to the particle spin. Nevertheless, the question about the true ground state of the electron liquid (i.e. spin polarized or unpolarized), just after the solid-liquid transition is currently under active discussion [26] and requires further investigation.

In the simulations presented below we assume that the electrons and holes can reach thermal equilibrium and are cooled down by using, e.g. ^3He or ^4He dilution refrigeration to a temperature of $k_B T = 1/3000 \text{ Ha}$. For ZnSe (GaAs) this corresponds to an absolute value of $T = 208.6 (44.37) \text{ mK}$. At these low temperatures thermal fluctuations are negligible and the system is practically in the ground state.

In the PIMC representation of the density matrix applied in our simulations [20], we have used 256 (in some cases 128) beads (high temperature factors). This was sufficient to reach convergence for the full energy better than 1% and an even better accuracy for the pair distribution functions. The use of such a moderate number of beads was only possible by using pre-computed tables of the pair density matrices for all types of Coulomb interactions, i.e. for the intra-layer and inter-layer interaction terms in the hamiltonian (1), and for the external parabolic confinement for both electrons and holes. To reduce the enormous computational effort for a simulation of fermions, here we used Boltzmann statistics for both electrons and holes, and the spin effects are omitted. For reasons discussed above we expect that this will not influence the results of this paper significantly.

Both layers are treated as pure 2D layers of zero thickness. Considering that the thickness of real physical QWs is of the order of few Bohr radii, this approximation seems to be reasonable for the range of densities considered here, i.e. $r_s = \hbar r/a_B \approx 10$, and an inter-layer distance of $d = 20a_B$. [The case when d and $\hbar r$ become comparable to the well width would require essentially more computationally costly 3D simulations and inclusion additional terms related to the QW potential in the hamiltonian (1)]. For quite narrow QWs with a thickness of about $1a_B$ and less, the adiabatic approximation can be successfully used with the 2D hamiltonian (1) with slightly changed interaction terms (see Ref. [27]).

For the chosen inter-layer distance, $d = 20a_B$, our system represents essentially a 3D structure, as the intra-layer and inter-layer correlations are on the same length and energy scales. For small ratios $d/r_s \approx 1$ the system approaches the single layer limit, whereas for $d/r_s \gg 1$, it behaves like two uncoupled layers. Also, for $d = 20a_B$ we can completely neglect the inter-layer tunneling, and the life time of electrons and holes can reach a few microseconds which is much larger than their equilibration time.

The mass ratio of the electrons and holes is varied in the range of $1 \leq m_h/m_e \leq 100$ which covers practically all semiconductor materials. In our simulations we have found that the initial equilibration time needed to bring the system from an initial randomly chosen configuration to the thermodynamic one, depends on the electron-hole mass ratio and the strength of the external confinement. Usually we skip the first $10\,000 - 100\,000 \text{ MC-steps}$ and only then start to accumulate thermodynamic averages.

2.2 Calculated quantities

2.2.1 Pair and radial distribution functions

The physically relevant quantities to investigate a phase transition are the *radial*, $n(r)$, and *pair* distribution function, $g(r)$. Both functions are a good probe of the short and long-range order in the system and yield information on the importance of correlation effects. In Statistical Mechanics these quantities are given by the expressions

$$g_{ab}(r) = \frac{1}{N_a N_b} \sum_{i=1}^{N_a} \sum_{j=1}^{N_b} \langle h(r_{ij} - r_0) \rangle; \quad n_{a(b)}(r) = \frac{1}{N_{a(b)}} \sum_{i=1}^{N_{a(b)}} \langle h(r_i - r_0) \rangle; \quad (2)$$

where a and b are two particle species, r_0 is the reference point for the radial density (e.g the center of the parabolic potential as used here), and $\langle \dots \rangle$ denotes the thermodynamic average. In the PIMC approach the averaging is performed with the N particle density matrix, i.e

$$\langle \dots \rangle = \frac{1}{Z} \int \dots dr_1 dr_2 \dots dr_N \quad (2.2) \quad (r_1; r_2; \dots; r_N; \dots) \quad (3)$$

After the high-temperature decomposition this integral includes also additional integrations over the particle coordinates on the intermediate “time-slices” and, as a result, the particle images on each time slice also contribute to the distribution function which significantly improves the convergence of the simulations.

2.2.2 Lindemann parameter

One of the criteria to investigate structural phase transitions (e.g., solid-liquid phase transition) was proposed by Lindemann [28], who used vibration of atoms in the crystal to explain the melting transition. The average amplitude of thermal vibrations increases with temperature of the solid. At some point the amplitude of the vibrations becomes so large that the atoms start to occupy the space of their nearest neighbors and disturb them, and the melting process is initiated. According to Lindemann, the melting might be expected when the root mean vibration amplitude $\sqrt{\langle u^2 \rangle}$ exceeds a certain threshold value ($\langle u^2 \rangle$ is the particle fluctuation from a lattice site, $a = 1/\sqrt{n}$, n is the density). Namely, when the amplitude reaches at least 10% of the nearest neighbor distance, this quantity exhibits a rapid growth when the temperature becomes close to the melting temperature of the solid phase. While for 3D systems this criterion can be successfully used, in 2D this quantity shows a logarithmic divergence, $\ln(L/a)$, with the increase of the system size L . Instead, to indicate the phase transition from a liquid to a crystal, in 2D, one should apply the modified Lindemann criterion and use the relative distance fluctuations [29]

$$u_r^{ab} = \frac{1}{N_a N_b} \sum_{i=1}^{N_a} \sum_{j=1}^{N_b} \frac{r_{ij}^2}{\langle r_{ij}^2 \rangle} \quad (4)$$

where r_{ij} is the distance between the particles i and j . To reduce the effect of particle diffusion through the cluster (in a finite system) or through the simulation cell (for a macroscopic system), which leads to very slow convergence with the increase of the system size, in the calculation of (4) we have performed partial averaging over 1 000 MC-steps (one block). After the current block has been completed we proceed to a new one and the MC averaging was repeated for the next 1 000 MC-steps. The difference in the fluctuations measured from block to block can characterize the ordering in the system and is more effective for large systems.

2.2.3 Nature of the phase transition in 2D systems

Strictly speaking, in classical macroscopic 2D systems at $T \neq 0$ a true crystal state does not exist. The absence of off-diagonal long range order in the system manifests itself in the existence of two disordered phases characterized by different asymptotic behaviours of the pair correlation function $g(r; r^0)$. The system undergoes a transition at a finite temperature T_{KT} (Kosterlitz-Thouless transition) when the asymptotes $g(r; r^0) \xrightarrow{r \rightarrow \infty} 1$ changes from

$$g(r; r^0) \sim \frac{\exp(-\frac{r}{\xi(T)})}{r^2} \quad (T > T_{KT}) \quad \text{to} \quad g(r; r^0) \sim \frac{1}{r^2} \quad (T < T_{KT}): \quad (5)$$

The important question of the relevance of the standard Kosterlitz-Thouless theory also for 2D *quantum* systems has been discussed in Ref. [32] for the two-dimensional XY model. A generalization for Coulomb systems is subject of ongoing work [33]. Concerning the interpretation of the results of the present publication we indeed find a abrupt transition in the decay of the maxima and minima of $g(r; r^0)$ (see the discussion below) which can be approximated by the asymptotes in Eq. (5).

3 Numerical results: Mesoscopic system

In the following we consider a bilayer system populated with a mesoscopic number of $N_e = N_h = 36$ electrons and holes. The results of our simulations are presented in Figs. 2-3. In our simulations two different densities are analyzed, given by $n = 5$ and $n = 10.5$ which corresponds to the first maxima of the pair distribution function $g_{hh}^{max} = 8.7$ and $g_{hh}^{max} = 19$, respectively. These densities are chosen such that, at the given temperature, hole crystallization is expected to occur, at least for large mass ratios $M = m_h/m_e$. If the density is chosen too low, the Coulomb coupling would be weak for crystallization. On the other hand, if the density is too high, the crystal vanishes due to quantum melting. At the chosen densities the electrons are always in the quantum liquid-like state, while the state of the holes can be changed by varying M .

At the chosen densities the total cluster radius is $R = 5 = 70a_B$ ($R = 10.5 = 150a_B$). That means that the average densities (in a single layer) are for GaAs $n = 5 = 9.4 \cdot 10^{10} \text{ cm}^{-2}$ and $n = 10.5 = 2.0 \cdot 10^{11} \text{ cm}^{-2}$, and for ZnSe $n = 5 = 9.9 \cdot 10^{10} \text{ cm}^{-2}$ and $n = 10.5 = 2.2 \cdot 10^{11} \text{ cm}^{-2}$. These values are for the electrons, for the holes the radius slightly decreases when M is increased.

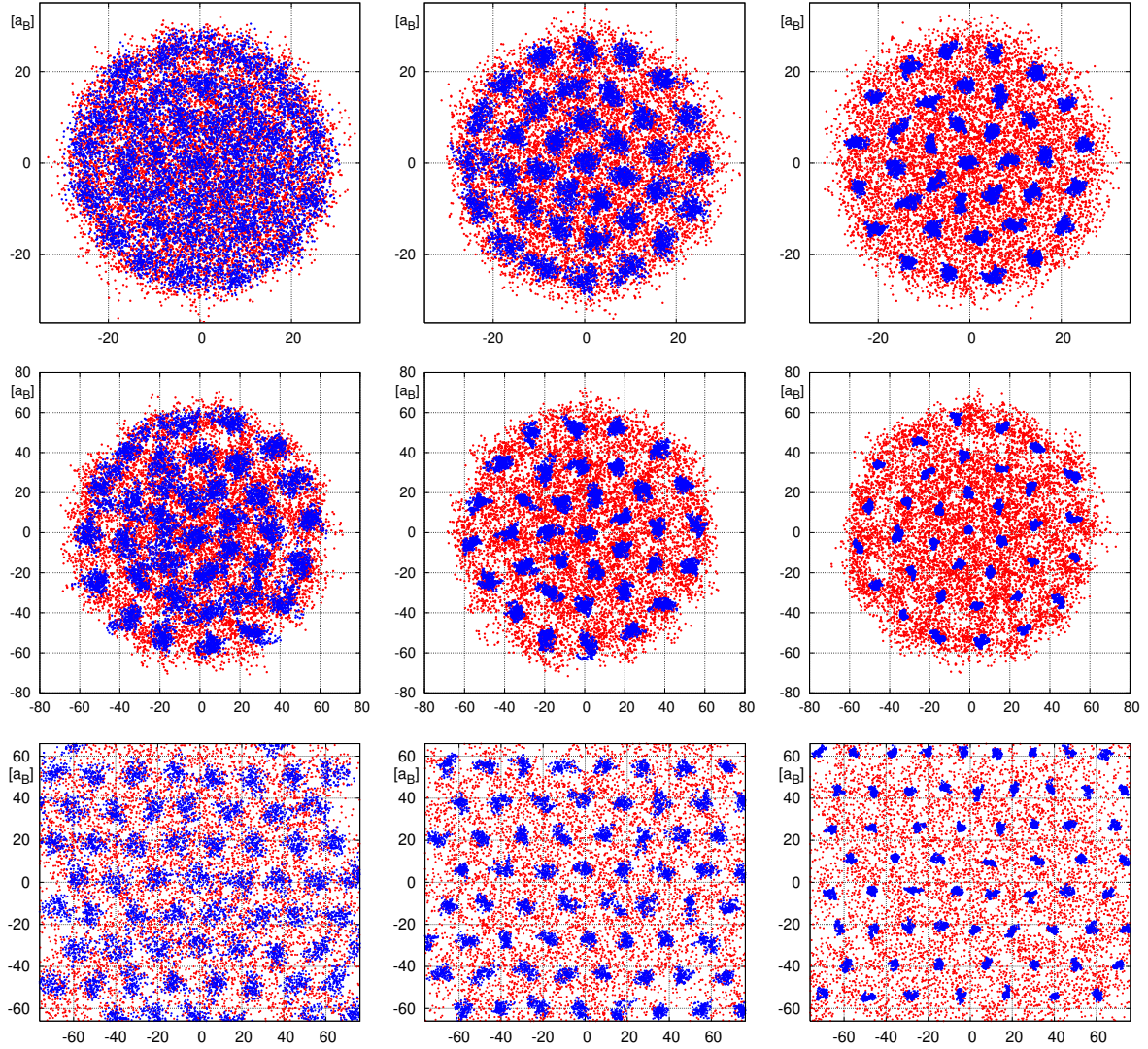


Fig. 1 (Color online) Path integral Monte Carlo configuration of holes (blue points) and electrons (red dots) in a bilayer system with distance $d = 20a_B$, temperature $T = \hbar \omega = 3000$ and different mass ratios: $M = 5$ (left column), $M = 20$ (center) and $M = 100$ (right). Each particle is represented by 256 dots (path integral) which, for the electrons, are mutually penetrating. *First two rows:* 36 electrons and holes in a harmonic trap with coupling strengths $\gamma = 5$ (upper panel) and $\gamma = 10.5$ (second panel). Shown is a typical snapshot (without statistical averaging). Note the different axis scales in the two panels. *Row 3:* Simulation snapshots of a macroscopic bilayer ($N_e = N_h = 64$ electrons and holes in the simulation cell with periodic boundary conditions, the borders mark the simulation cell. Each particle is shown only once). The density matches the one in the confined system of the second row. There are structural defects as the triangular lattice is not uniform.

Consider first Fig. 1 which gives an overview on the observed behavior for the two densities (first two rows) when the mass ratio is varied in the range from 1 to 100. The first observation is that, in all cases, the electrons are distributed almost continuously, whereas the holes become localized when M exceeds 20 (5) at $\gamma = 5$ (10.5). Due to the rotational symmetry of the trap, the holes are arranged in concentric shells.

The main difference between the mesoscopic system with a parabolic inplane confinement and an infinite system are well-known finite size effects, see e.g. [34] which are related to the rotational symmetry instead of translational symmetry. Further, even when averaged over the modulation caused by the shells the density is not constant over the entire system, cf. left part of Fig. 2. The average density is highest in the center and decreases

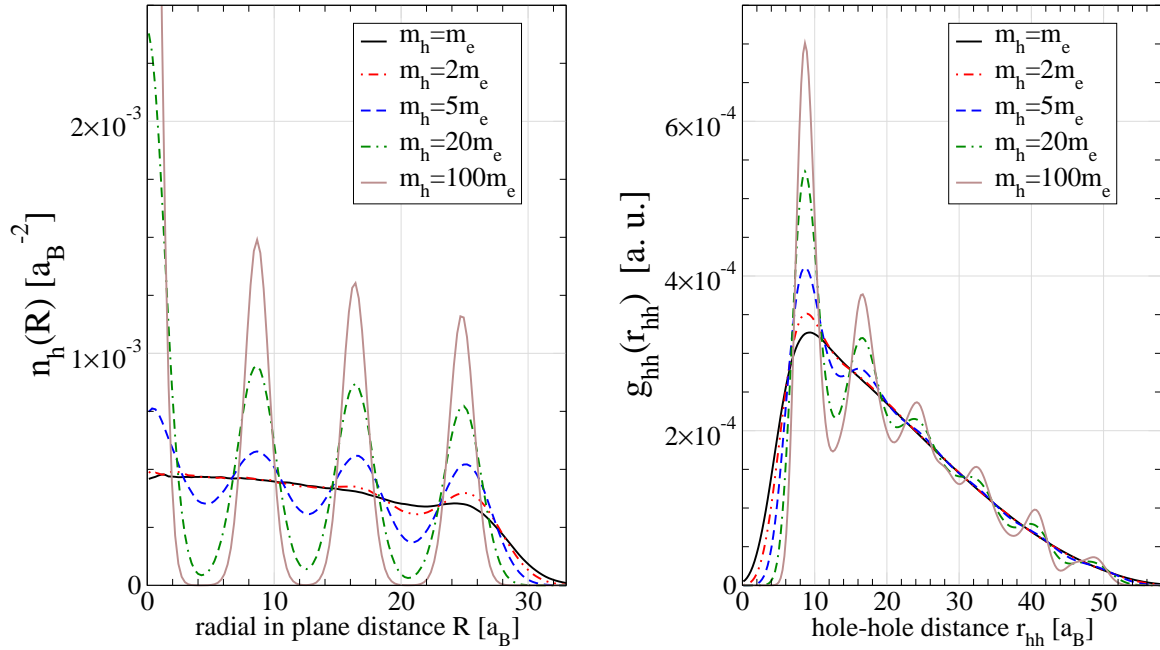


Fig. 2 (Color online) Hole radial distribution (left fig.) and hole-hole pair distribution (right) for $\beta = 5$ and five mass ratios (see inset) for a mesoscopic confined bilayer with $N_e = N_h = 36$.

towards the cluster surface. Fig. 2 also clearly shows the effect of the mass ratio. With increasing M the hole-hole correlations increase leading to increased hole localization [5, 6]. This is accompanied by a pronounced modulation of the radial density $n(R)$ and the pair distribution (PDF) g_{hh} , see Fig. 2. The reduction of the zero point fluctuation with increase of the particle mass M leads to a hole localization and crystal formation. It is found that the shell radii in the radial density profile $n(R)$ in Fig. 2, as well as the peak positions in the hole-hole pair correlation function g_{hh} of the mesoscopic cluster ($\beta = 5$) are independent from mass ratio M . For $M = 100$ we find that the holes are arranged in 3 shells populated with 16, 12, 7 and a single particle in the center, see Fig. 1.

Fig. 2 shows, that by changing the mass ratio from 1 to 100 the holes exhibit a transition from a delocalized quantum state with wave function overlap to a highly ordered quasi classical state, while the electrons stay in a quantum fluid state and their correlations change only little with M for the present parameters. We note that the classical Coulomb coupling parameter for $M = 100$ is $\beta = 5 = \hbar U_{\text{corr}} / \hbar U_{\text{kin}} = 345$ and $\beta_{10:5} = 158$, which is beyond the critical value for the macroscopic (OCP) crystallization $\beta_{\text{crit}} = 137$.

Let us now consider the response of the electrons to the formation of the hole crystal. While the electron density is almost structureless, some details can be seen in the electron-hole PDF, Fig. 3. This function has a distinct peak at zero (in-plane) distance showing the electrons and hole are pairwise vertically aligned for all values of M . Also, the next peaks of the e-e PDF are aligned with those of g_{hh} . The small shift in the peaks of the two functions is due to the normalization. In order to compare the details of the cluster arrangements with the macroscopic system below, in Fig. 3 we have divided g_{hh} and g_{eh} by the corresponding functions for $M = 1$ where they are structureless. This allows to largely eliminate the effect of the trap (but slightly shifts the extrema).

4 Numerical results: Macroscopic system

To understand the relevance of our above mesoscopic results for larger systems containing hundreds or thousands of particles we performed additional simulations for a macroscopic e-h bilayer without confinement potential. We have considered $N_e = N_h = 64$ electrons and holes in a simulation cell of the size $fL_x \times L_y \times g = f76:185a_B \times 65:978a_B \times g$ with periodic boundary conditions (PBC). This corresponds to a density parameter $r_s \approx 10$ (average particle distance in units of the electron Bohr radius). This density was chosen to be comparable to the average

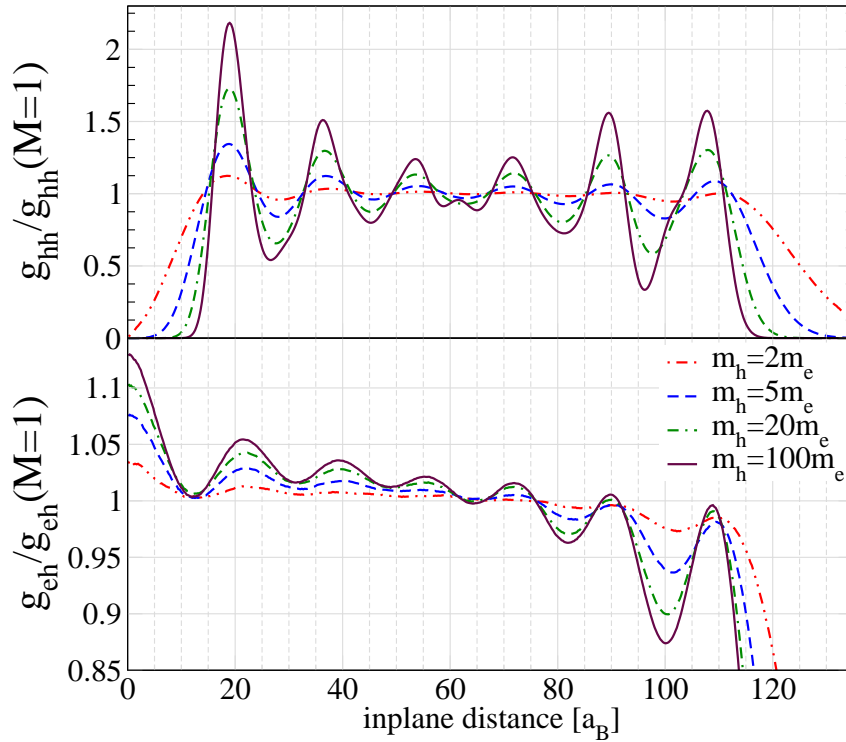


Fig. 3 Hole-hole (upper fig.) and electron-hole (lower fig.) pair distribution functions for the *mesoscopic* bilayer with $N_e = N_h = 36$ and $\beta = 10.5$ for four values of M (see inset). The curves are normalized to the corresponding PDF for the case $M = 1$ to eliminate the influence of the decay of the average density in the trapped system, cf. Fig. 2. Note that electrons and holes are always pairwise aligned vertically. The plot includes distances up to two times the radius which causes the increase of the PDF for large distances.

density in the finite system (see Sec. 3) for the case of coupling parameter $\beta = 10.5$. The mass ratio M was varied between 1 and 100, the temperature was fixed to $kT = 1/3000$ a. The number of particles and the dimensions of the cell, i.e. $L_y = \sqrt{3}L_x = 2$, were chosen to best fit the symmetry of a triangular lattice, which is expected to be formed by the holes. We note that finite size effects are of the order of few percents, a systematic analysis with larger particle numbers is beyond the scope of this paper.

Let us now consider the results for the macroscopic bilayer. Three typical snapshots for $M = 5; 20; 100$ are shown in the lower row of Fig. 1. As in the mesoscopic system, for all cases the electrons are completely delocalized. In contrast, the hole localization increases from $M = 5$ to $M = 100$. Also, we confirm that the density of the mesoscopic system (second row) is well matched: the average distance between two holes as well as their extension (given by the size of the blue dots) is very close to the trapped case.

Consider now the pair distributions. In Fig. 4 (upper fig.) we show the hole-hole PDF for different mass ratios $1 \leq M \leq 20$. Since the particle number and box size is fixed, the average particle density stays constant and the position of the first peak of the PDF are practically independent of M . However, the general behavior of the PDF changes drastically. For $M \geq 4$ we observe clear oscillations typical for the solid phase. Even the third and fourth peaks are well resolved (the scale exceeds half of our simulation box). These oscillations become rapidly damped by changing M to 3 and below, here the PDF show liquid-like features. The third peak is now strongly suppressed. This transition can be quantified by computing the ratio of the (magnitude of the) first minimum to the first maximum which is $r_1 = 0.48$, for $M = 4$, and $r_1 = 0.65$, for $M = 3$. Similarly, for the third peak this ratio becomes $r_3 = 0.76$ and $r_3 = 0.96$, respectively. The ratio r_1 is frequently used as an empirical criterion for the solid-liquid transition in classical systems; in a one-component 3D system the critical value is known to be $r_1 = 1/3$. If a universal values exists also in the present two-component 2D quantum system where the transition is expected to be of the Kosterlitz-Thouless type is an interesting question which deserves further analysis.

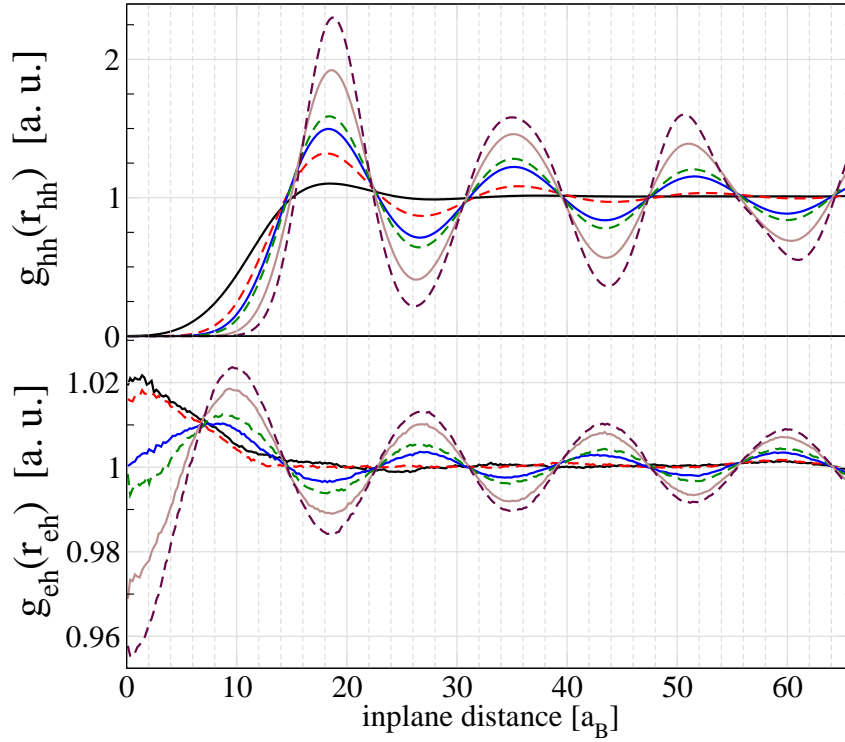


Fig. 4 Hole-hole (upper fig.) and electron-hole (lower fig.) pair distribution functions for the *macroscopic* bilayer with $N_e = N_h = 64$ (with periodic boundary conditions) for the mass ratios $M = 1; 3; 4; 5; 10; 20$ (the maxima increase with increasing M). Note the alternating location of maxima and minima of g_{hh} and g_{eh} .

Let us now compare the pair distributions with those in the mesoscopic system at the same density ($\rho = 10^{-5}$), Figs. 4 and 3. Interestingly, we find that the first peaks of g_{hh} have approximately the same height, and also the peak positions are very close, see upper parts of the two figures. Further we observe that the minima of g_{hh} are significantly deeper in the macroscopic case. This is explained by intershell rotations which occur in the mesoscopic system [5] and wash out the correlations. The present results are at temperatures above the freezeout of these rotations.

Consider now the relative importance of the inter-layer correlations for the stability of the hole crystal. To this end, we have plotted the e-h PDF in Fig. 4 (lower fig.). For the symmetric case, $M = 1$, and also for $M = 3$ we observe similar behavior: the highest probability has the configuration where the electrons reside (in their own layer) just below the holes, as was observed in the mesoscopic system, lower part of Fig. 3. Obviously, the height of this peak is small, the modulation depth is around 2% because of the high electron degeneracy (delocalization). This means that these peaks cannot be associated with bound states (indirect excitons) since the electron density is well above the Mott density n_{Mott} for this system where excitons break up because the repulsion of two excitons exceeds the electron-hole binding. Note that n_{Mott} depends on the layer separation d which governs the binding energy and the typical size a_B^x of an indirect exciton which is of the order of d . Hence, for the present parameters, $d = a_B = 20$ and $r_s = 10$, the in-plane exciton size exceeds the separation of two neighboring electrons which causes exciton ionization. On the other hand, reducing d below 10, excitons become stable (for temperatures below the exciton binding energy) which is confirmed by our PIMC simulations.

For larger mass ratios, $M \geq 4$, a completely different behavior of g_{eh} emerges. From our analysis of the hole-hole correlations we know that the holes are now in an “ordered state” (or, in the terms of the Kosterlitz-Thouless theory, in a “less disordered state” with a power-law decay of off-diagonal long-range order). Now, there is no maximum of g_{eh} at zero distance, and the function exhibits oscillations. The explanation is that the electron density is modulated due to the presence of the hole crystal with maxima located in between the holes. While the amplitude of the oscillations is small, (about 1% modulation depth) they are clearly visible

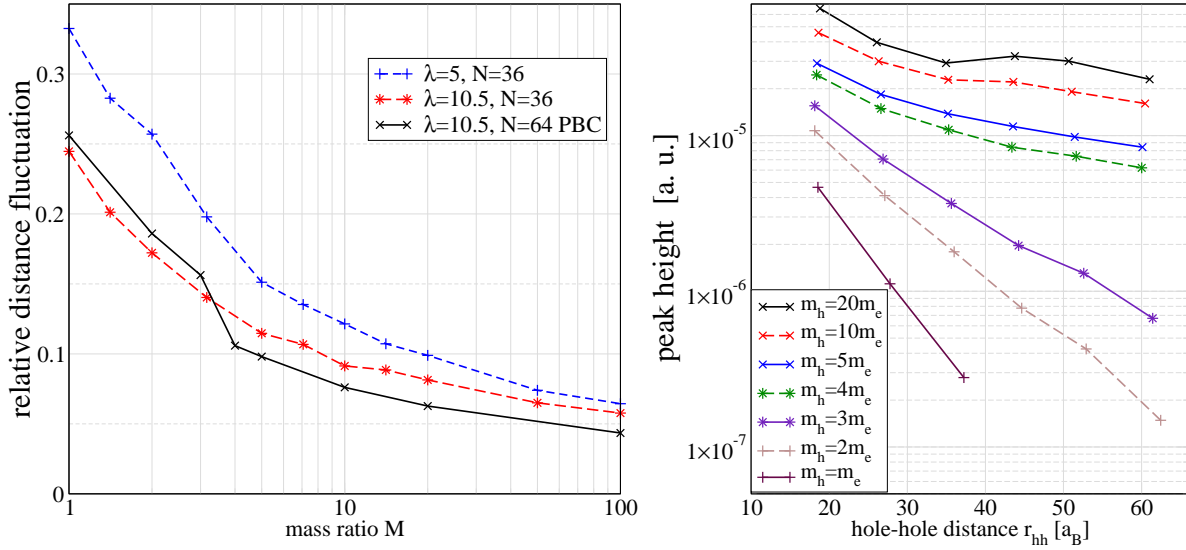


Fig. 5 (Color online) Left Fig.: Relative distance fluctuations of the holes, u_r^{hh} , (Eq. 4), as a function of the mass ratio M for a macroscopic (black solid line) and mesoscopic bilayer system for two densities (see inset). Right Fig.: Decay of the amplitude of the maxima and minima of the hole correlations ($\langle \tilde{g}_{hh} - 1 \rangle$) in the macroscopic system, cf. Fig. 4, for the seven mass ratios – from bottom to top: $M = 1; 2; 3; 4; 5; 10; 20$. Note the change from an exponential (for $M \leq 3$) to a power law decay (for $M \geq 4$) which signals the Kosterlitz-Thouless transition.

and become systematically more pronounced when M increases, see Fig. 4 (lower part). We, therefore, expect that appearance (disappearance) of these oscillations of g_{eh} is an additional indicator of a phase transition in the present asymmetric bilayer system.

Finally, as another quantity sensitive to phase transitions, we consider the relative distance fluctuations u_r^{hh} of the holes, Eq. 4, as a function of M , Fig. 5 (right part). This quantity exhibits a rapid drop between $M = 3$ and $M = 4$ which is related to a localization transition. We can translate from the critical mass ratio (which is expected to be between three and four) to the hole density parameter $r_s^{(h)}$, using $r_s^{(h)} = r_s^{(e)} m_h / m_e$, and the position of the first peak of the hole-hole PDF at $r_s^{(e)} \approx 10$. As a result, we obtain that the phase transition in the hole layer occurs at a critical density in the range $30 < r_s^{(h)} < 40$. This result is close to the value $r_s \approx 37$ known as the critical density of solid-liquid transition in the one-component quantum 2D system at $T = 0$ [24]. Compared to this value, in our bilayer system, we observe indications of stabilization of the “ordered state” of the holes due to presence of the electron layer.

We note that, at smaller values of d (e.g. $d = 5a_B$ and $d = 10a_B$) no hole crystal is found. Instead we observe formation of indirect excitons which form a solid phase of composite particles. At the same time, the interparticle interaction changes from Coulomb to dipole-like which reduces the value of the classical coupling parameter to $\gamma = \frac{e^2 d^2}{\hbar r^3} = k_B T$. Similar tendencies have also been also in simulations of *symmetric* classical and quantum e-h-bilayers [11, 14].

5 Discussion

Analyzing the peak height (amplitude) of the g_{hh} in the macroscopic system (Fig. 4) in dependence on the peak position r_{hh} we can deduce the correlation decay law and compare to the asymptotics (5). In the disordered phase of small mass ratios $M = 1 \dots 3$ we find an exponential correlation decay of g_{hh} , see right part of Fig. 5. From mass ratio $M = 1$ to $M = 3$ disordering is lowered and the correlation length increases from $\xi = 6.5$ to $\xi = 13$. Increasing the mass ratio above the critical mass ratio, i.e. $M \geq 4$, we find a topological transition to the Kosterlitz-Thouless phase with power law correlation fall-off.

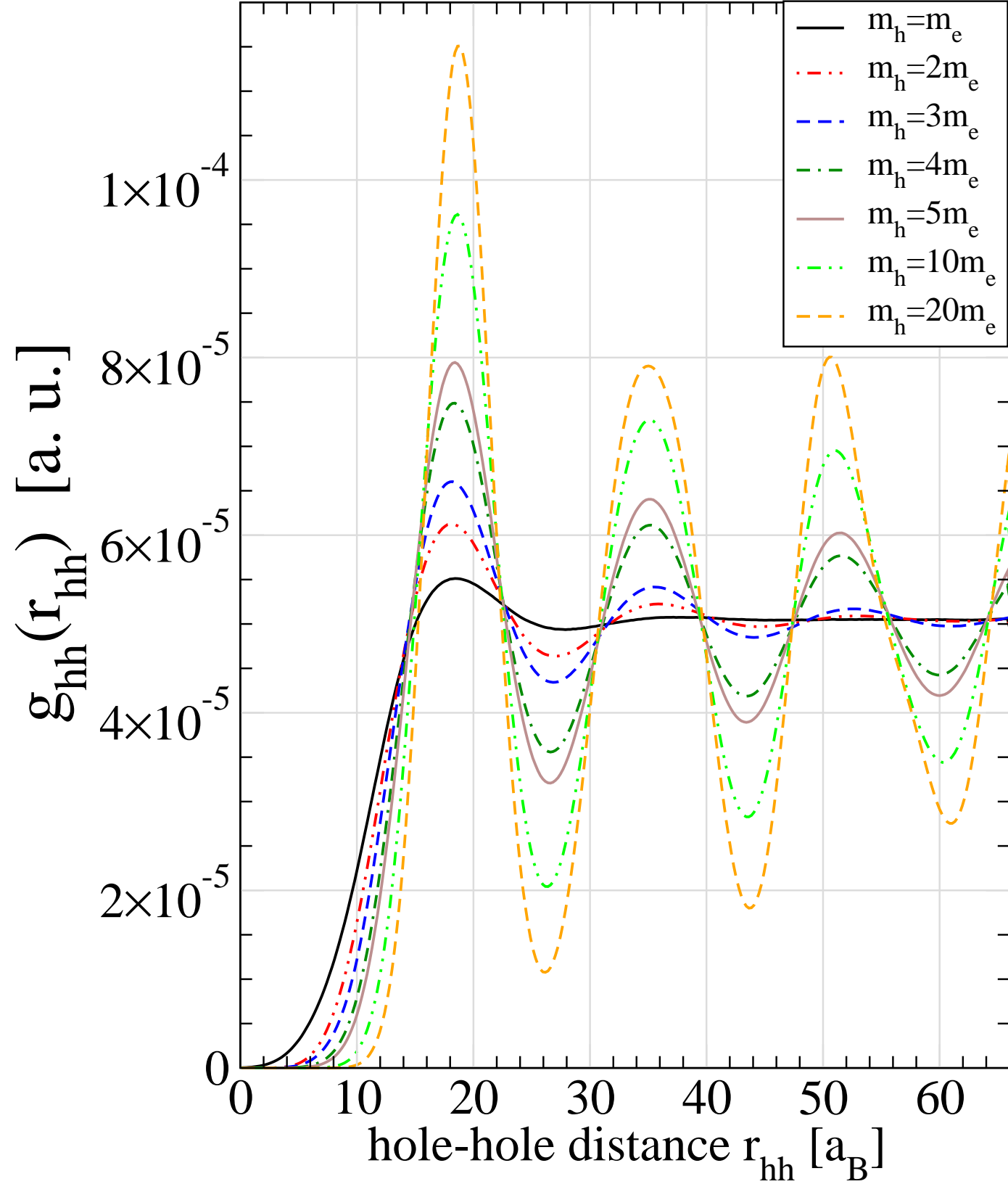
We may now obtain a critical mass ratio at which quantum melting of the hole crystal takes place. Using as a criterion a critical value of $u_r = 0.15$ of the relative hole-hole distance fluctuations we obtain $M_{crit} (\gamma = 5) \approx 5$

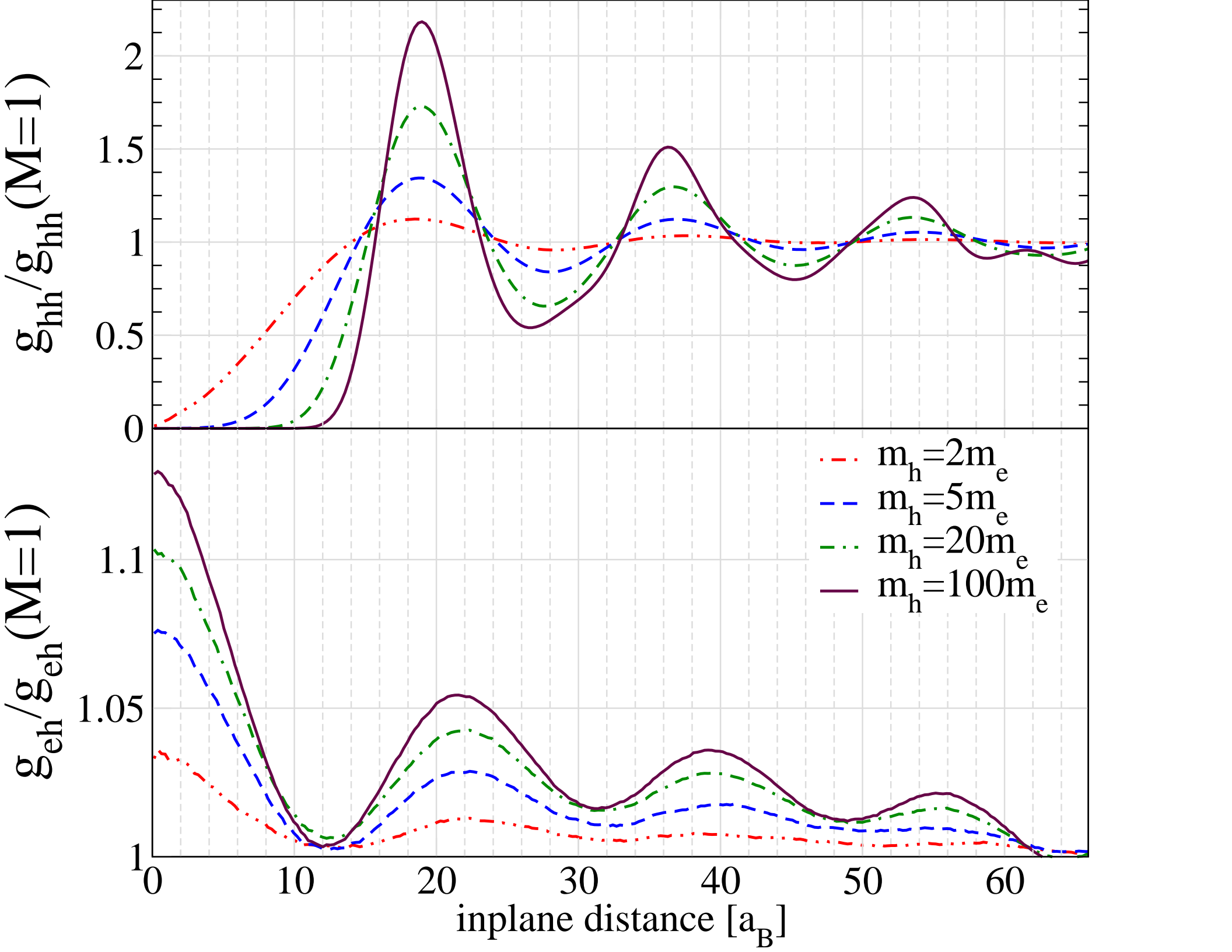
and $M_{\text{crit}} (r_s = 10.5) \approx 2.8$, in the mesoscopic system, and $M_{\text{crit}} (r_s = 10) \approx 3.1$, in the macroscopic system (recall that it corresponds to $r_s = 10.5$). Obviously, the absolute numbers are somewhat arbitrary, but they allow for an analysis of the dominant trends. i) M_{crit} depends on density. It decreases when the coupling strength increases in agreement with earlier observations for small e-h clusters [23]. ii), there is good agreement between the critical mass ratios of the mesoscopic and the macroscopic system (within 10%). iii) the critical values are much smaller than the value of $M_{\text{crit}} \approx 80$ in a 3D bulk system [7] which underlines the remarkable additional control of physical behaviors existing in a bilayer system by a variation of the layer separation d . It is expected that further reduction of d will allow to further reduce M_{crit} and to increase the maximum density of the hole crystal to values below $r_s^{(h)} = 20$ [15].

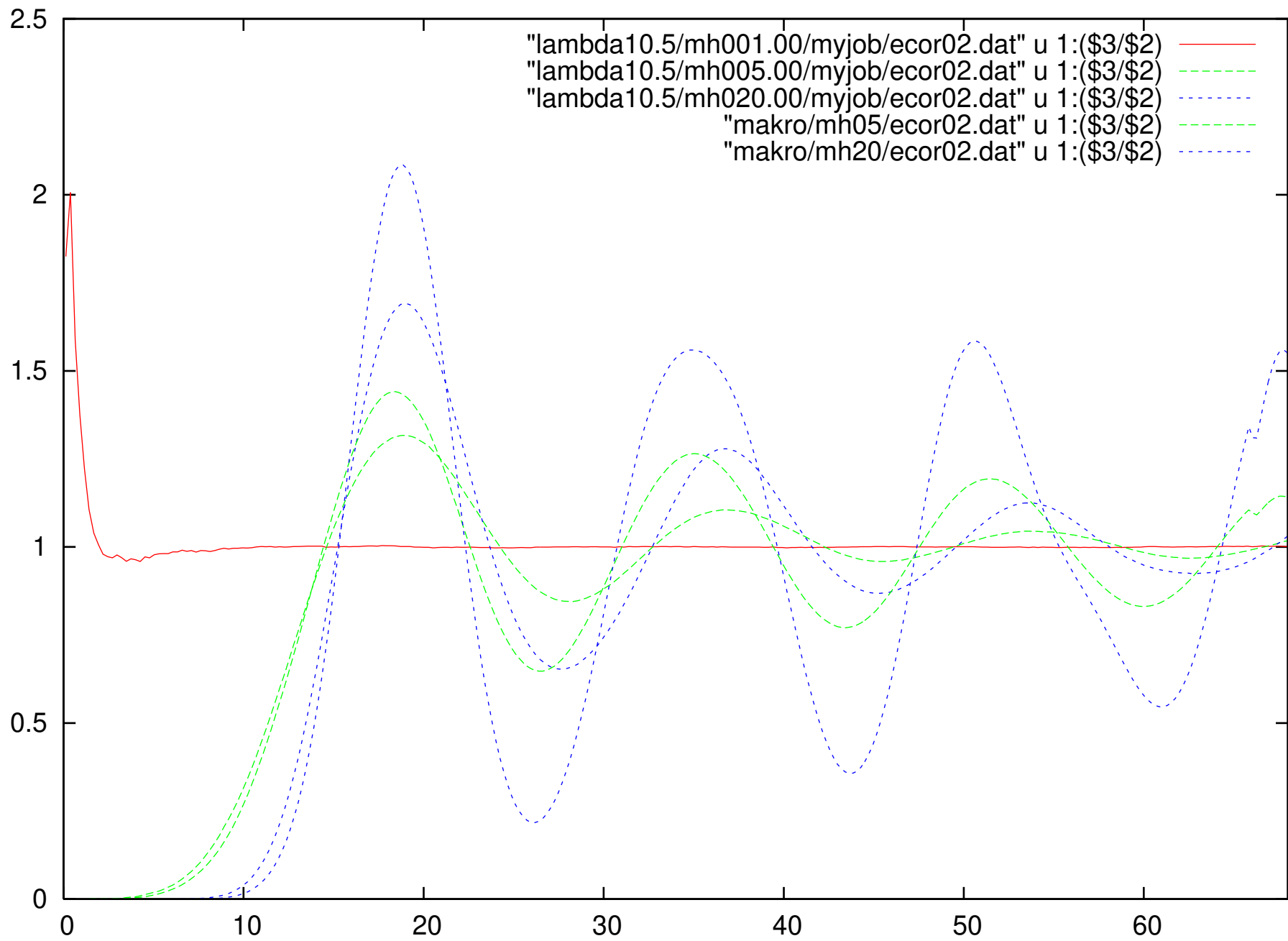
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Greek symbols { w-greek.sty

α	<code>\alpha</code>	θ	<code>\theta</code>	\circ	<code>\circ</code>	τ	<code>\tau</code>
β	<code>\beta</code>	ϑ	<code>\vartheta</code>	π	<code>\pi</code>	υ	<code>\upsilon</code>
γ	<code>\gamma</code>	ι	<code>\iota</code>	ϖ	<code>\varpi</code>	ϕ	<code>\phi</code>
δ	<code>\delta</code>	κ	<code>\kappa</code>	ρ	<code>\rho</code>	φ	<code>\varphi</code>
ϵ	<code>\epsilon</code>	λ	<code>\lambda</code>	ϱ	<code>\varrho</code>	χ	<code>\chi</code>
ε	<code>\varepsilon</code>	μ	<code>\mu</code>	σ	<code>\sigma</code>	ψ	<code>\psi</code>
ζ	<code>\zeta</code>	ν	<code>\nu</code>	ς	<code>\varsigma</code>	ω	<code>\omega</code>
η	<code>\eta</code>	ξ	<code>\xi</code>				
Γ	<code>\Gamma</code>	Λ	<code>\Lambda</code>	Σ	<code>\Sigma</code>	Ψ	<code>\Psi</code>
Δ	<code>\Delta</code>	Ξ	<code>\Xi</code>	Υ	<code>\Upsilon</code>	Ω	<code>\Omega</code>
Θ	<code>\Theta</code>	Π	<code>\Pi</code>	Φ	<code>\Phi</code>		

Table 1: Slanted greek letters

α	<code>\upalpha</code>	θ	<code>\uptheta</code>	\circ	<code>\upcirc</code>	τ	<code>\uptau</code>
β	<code>\upbeta</code>	ϑ	<code>\upvartheta</code>	π	<code>\uppi</code>	υ	<code>\upupsilon</code>
γ	<code>\upgamma</code>	ι	<code>\upiota</code>	ϖ	<code>\upvarpi</code>	ϕ	<code>\upphi</code>
δ	<code>\updelta</code>	κ	<code>\upkappa</code>	ρ	<code>\uprho</code>	φ	<code>\upvarphi</code>
ϵ	<code>\upepsilon</code>	λ	<code>\uplambda</code>	ϱ	<code>\upvarrho</code>	χ	<code>\upchi</code>
ε	<code>\varepsilon</code>	μ	<code>\upmu</code>	σ	<code>\upsigma</code>	ψ	<code>\uppsi</code>
ζ	<code>\upzeta</code>	ν	<code>\upnu</code>	ς	<code>\upvarsigma</code>	ω	<code>\upomega</code>
η	<code>\upeta</code>	ξ	<code>\upxi</code>				
Γ	<code>\Gamma</code>	Λ	<code>\Lambda</code>	Σ	<code>\Sigma</code>	Ψ	<code>\Psi</code>
Δ	<code>\Delta</code>	Ξ	<code>\Xi</code>	Υ	<code>\Upsilon</code>	Ω	<code>\Omega</code>
Θ	<code>\Theta</code>	Π	<code>\Pi</code>	Φ	<code>\Phi</code>		

Table 2: Upright greek letters

$\bm{\alpha}$		$\bm{\theta}$	\mathfrak{o}	$\bm{\tau}$
$\bm{\beta}$	#	$\bm{\vartheta}$	$\bm{\pi}$	$\bm{\upsilon}$
$\bm{\gamma}$		$\bm{\iota}$	\mathfrak{p}	$\bm{\phi}$
$\bm{\delta}$		$\bm{\kappa}$	$\bm{\rho}$	$\bm{\varphi}$
$\bm{\epsilon}$		$\bm{\lambda}$	\mathfrak{r}	$\bm{\chi}$
"		$\bm{\mu}$	$\bm{\sigma}$	$\bm{\psi}$
$\bm{\zeta}$		$\bm{\nu}$	\mathfrak{s}	$\bm{\omega}$
$\bm{\eta}$		$\bm{\xi}$		
$\bm{\Gamma}$		$\bm{\Lambda}$	$\bm{\Sigma}$	$\bm{\Psi}$
$\bm{\Delta}$		$\bm{\Xi}$	$\bm{\Upsilon}$	$\bm{\Omega}$
$\bm{\Theta}$		$\bm{\Pi}$	$\bm{\Phi}$	

Table 3: Boldface variants of slanted greek letters

α	$\pmb{\alpha}$	θ	$\pmb{\theta}$	\mathfrak{o}	$\pmb{\mathfrak{o}}$	τ	$\pmb{\tau}$
β	$\pmb{\beta}$	ϑ	$\pmb{\vartheta}$	π	$\pmb{\pi}$	υ	$\pmb{\upsilon}$
γ	$\pmb{\gamma}$	ι	$\pmb{\iota}$	ϖ	$\pmb{\varpi}$	ϕ	$\pmb{\phi}$
δ	$\pmb{\delta}$	κ	$\pmb{\kappa}$	ρ	$\pmb{\rho}$	φ	$\pmb{\varphi}$
ϵ	$\pmb{\epsilon}$	λ	$\pmb{\lambda}$	\mathfrak{r}	$\pmb{\mathfrak{r}}$	χ	$\pmb{\chi}$
"	$\pmb{"}$	μ	$\pmb{\mu}$	σ	$\pmb{\sigma}$	ψ	$\pmb{\psi}$
ζ	$\pmb{\zeta}$	ν	$\pmb{\nu}$	\mathfrak{s}	$\pmb{\mathfrak{s}}$	ω	$\pmb{\omega}$
η	$\pmb{\eta}$	ξ	$\pmb{\xi}$				
Γ	$\bm{\Gamma}$	Λ	$\bm{\Lambda}$	Σ	$\bm{\Sigma}$	Ψ	$\bm{\Psi}$
Δ	$\bm{\Delta}$	Ξ	$\bm{\Xi}$	Υ	$\bm{\Upsilon}$	Ω	$\bm{\Omega}$
Θ	$\bm{\Theta}$	Π	$\bm{\Pi}$	Φ	$\bm{\Phi}$		

Table 4: Boldface variants of upright greek letters